



Non-linear Thermo-Optical Properties of MoS₂ Nanoflakes by Means of the Z-Scan Technique

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OPEN ACCESS

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Specialty section:

This article was submitted to
Optics and Photonics,
a section of the journal
Frontiers in Physics

Received: 15 January 2020

Accepted: 13 March 2020

Published: 03 April 2020

Citation:

Mirershadi S, Sattari F, Alipour A and
Mortazavi SZ (2020) Non-linear
Thermo-Optical Properties of MoS₂
Nanoflakes by Means of the Z-Scan
Technique. *Front. Phys.* 8:96.
doi: 10.3389/fphy.2020.00096

The non-linear thermo-optical response of MoS₂ nanoflakes was investigated using the Z-scan technique, employing TM00-mode with a CW-laser diode operating at a wavelength of 532 nm. The systems were found to display a strong non-linear response, dominated by non-linear refraction. The effect of the thickness of the MoS₂ layer, deposited on a glass substrate, on the non-linear susceptibility was studied. Furthermore, in this study, the effects of modifying the thickness of the MoS₂ nanoflakes on the non-linear optical phenomena, such as self-focusing and self-defocusing was investigated for the first time. In all cases, the non-linear absorption and refraction were determined. The corresponding third-order susceptibilities and second-order hyperpolarizability were calculated to be as large as 10⁻⁷ (esu) and 10⁻³² (esu), under laser excitation, respectively. Showing large third-order optical non-linearity suggests the potential of the MoS₂ nanoflakes in photonics applications.

Keywords: Z-scan technique, non-linearity, refractive index, MoS₂, non-linear susceptibility, hyperpolarizability

INTRODUCTION

For the past few decades, the subjects that have stolen the spotlight of the theoretical and experimental interests are the linear and non-linear optical response of semiconductors [1, 2]. Recently, among the novel two-dimensional (2D) materials, transition metal dichalcogenides (TMDCs) with the general formula MX₂, where M refers to a transition metal and X refers to a chalcogen (S, Se, or Te), has shown particularly promising electronic and optoelectronic properties [3–5]. Molybdenum disulfide (MoS₂) is one of the most typical TMDCs. A monolayer of MoS₂ is a semiconductor with a direct bandgap of 1.8 eV [6]. This property of MoS₂ can largely compensate for the weakness of the gapless graphene, which is an essential factor in making it possible to be used in the next-generation switching, optoelectronic and photonic devices, such as optical limiters, mode-lockers, and Q-switchers [7, 8]. A wide range of research has been conducted on the non-linear properties of few-layer MoS₂ structures including saturable absorption, non-linear absorption and non-linear refraction [9–11].

However, realizing the photophysical properties and discovering the potential for usage of few-layer MoS₂ compounds in optical applications come hand in hand with studying the non-linear optical properties of these structures. There are various techniques for measuring the non-linear refractive index. The Z-scan is a sensitive and standard technique that offers simplicity and high sensitivity and was the technique employed for measuring the sign and the magnitude of the non-linear refractive index, as well as the non-linear absorption coefficient [12–15].

A methodical first-principles study of the second-order non-linear optical properties of the MX_2 ($M = \text{Mo}$, W and $X = \text{S}$, Se) was carried out by Chung-Yu Wang et al. [16]. They demonstrated that the second-order non-linear optical susceptibility [$\chi^{(2)}$] of the MX_2 monolayer, over the whole range of the optical photon energy, is large and comparable to that of GaAs. Zhang et al. [17] used the Z-scan technique at various wavelengths, with femtosecond pulses. They examined the layer number and the excitation wavelength effects on the optical non-linearity of mono- and few-layers of WS_2 and MoS_2 , and discovered that the monolayer WS_2 exhibited high optical nonlinearities, having a two-photon absorption coefficient of $\sim 1.0 \times 10^4$ cm/GW. Moreover, Nitesh Dhasmana et al. demonstrated a dual absorption characteristic of the exfoliated MoS_2 dispersed in 1-Methyl-2-pyrrolidinone using an open aperture Z-scan technique [18]. They showed that, due to non-linear optical scattering, a saturable absorption in MoS_2 , at low fluences, and a deviation from this saturable absorption, at higher fluences, can be observed. Zhang et al. experimentally verified that MoS_2 has a broadband saturable absorption response from visible to the near-infrared band [19]. They also demonstrated the first ultrafast photonics application of MoS_2 saturable absorber for passive laser mode-locking operation, and experimentally, generated nanosecond pulses. They showed that, contrary to other saturable absorbers similar to graphene, the MoS_2 saturable absorber has excellent mode-locking ability. Non-linear optical properties of WS_2 and MoS_2 , obtained from both open and closed aperture Z-scan techniques using a picosecond mode-locked Nd: YAG laser operating at a wavelength of 1,064 nm, were investigated by Bikorimana et al. [20]. Both WS_2 and MoS_2 showed non-linear saturable absorption, whereas WSe_2 and $\text{Mo}_{0.5}\text{W}_{0.5}\text{S}_2$ exhibited non-linear two-photon absorption. A large two-photon absorption coefficient, β , as high as $+1.91 \times 10^{-8}$ cm/W was attained for $\text{Mo}_{0.5}\text{W}_{0.5}\text{S}_2$, and a non-linear refractive index of $n_2 = -2.47 \times 10^{-9}$ cm²/W was determined for the WSe_2 sample.

In the previous works, the structural and optical properties of the MoS_2 nanoflakes, grown on different substrates, such as silicon and quartz, by one-step thermal chemical vapor deposition were studied [21, 22]. In addition, the Z-scan technique was employed to study the non-linear optical properties of the obtained nanoflakes [22].

Here, the non-linear thermo-optical properties of MoS_2 nanoflakes, deposited on a glass substrate with various layer thickness, using the Z-scan technique, employing CW-laser diodes operating at 532 nm wavelength, were investigated. From the open-aperture Z-scan data it was realized that these two-dimensional structures exhibit two-photon absorption. The sign and the magnitude of the third-order non-linearity, by the means of the closed aperture Z-scan, was estimated.

EXPERIMENTAL

Preparation of Materials

Thin films containing mono and few-layer MoS_2 were synthesized by one-step thermal chemical vapor deposition on Si/SiO₂ substrate. Details of the experimental procedures

were described elsewhere [22]. First, in order to remove the native oxides from the silicon substrates, these substrates were soaked in hydrofluoric acid (HF) (10%). Then, by means of RF magnetron sputtering, 200 nm SiO₂ was sputtered on the substrates. Afterward, the MoO₃ powder (MERCK 99.5%, 50 mg) was collected in a ceramic boat and put in the highest-temperature thermal zone of the tube. The sulfur powder (TITRACHEM 99.0%, 500 mg) in another ceramic boat, near gas flow direction, was placed at the lower-temperature entrance of the tube (150–200°C). The substrate was placed face down on top of the boat containing MoO₃ in the hot zone. The furnace was heated from the room temperature up to 900°C within 20 min (45°C/min), in Ar gas flow (400 sccm) for 30 min. In order to start the reaction of the precursors under the Ar gas flow of 200 sccm as the carrier gas, the final temperature was kept constant for 1 h, and finally, the furnace was cooled to room temperature.

For the Z-scan measurement and the subsequent investigation of the effect of the MoS_2 layer's thickness on the non-linear optical properties, the following procedures were carried out. First, the prepared thin film was immersed in the solution of ethanol (64%) and DI water (36%) and treated by an ultrasonic homogenizer, with the power of 80 W for 15 min. The treated solution was drop cast on a glass substrate and dried in atmospheric condition. In principle, film thickness depends on the volume of the solution dispersed. In this work, films with thicknesses of 150, 230, and 420 nm (sample 1, sample 2, and sample 3, respectively) were achieved using different volumes of the solution.

CHARACTERIZATION TECHNIQUES

Structure and the Bragg reflections of the MoS_2 nanoflake were characterized by X-ray diffraction (XRD) (Cu K α X-ray radiation source, Ital structure model MPD 3000), with 2θ within the range of 2–70°. The scanning speed and step intervals were 1°/min and 0.02°, respectively. UV-visible diffuse reflectance spectra (UV-Vis DRS) were recorded on a Sinco S4100 spectrophotometer. The thickness of the thin films of the MoS_2 structure was measured using Dektak XT Profilometer (Bruker). Scanning electron microscopy (SEM) (LEO 1430VP) and atomic force microscopy (AFM) (Nanosurf) were used to determine the morphology and roughness of the thin films of the MoS_2 nanoflake, respectively.

Non-linear Optical Measurement

The third-order non-linear optical properties of the two-dimensional MoS_2 structure were measured using the single-beam Z-scan technique. Briefly, the Z-scan technique depends on the evaluation of the transmission of a sample when it is irradiated by a focused Gaussian laser beam and its position is translated through the beam waist along the propagation direction. As the sample experiences different laser intensities at different positions, the recordings of the transmission, as a function of the Z coordinate, provide information about the third-order non-linear effects [12]. The two measurable quantities are non-linear absorption and non-linear refraction. The non-linear absorption is determined by the “open-aperture”

Z-scan, while the non-linear refraction is measured using the “closed-aperture” Z-scan. Furthermore, this technique gives the real and the imaginary parts of the third-order susceptibility, $\chi^{(3)}$, second-order hyperpolarizability, γ , and also provides important information regarding the non-linear optical properties of the materials [12]. A diode laser operating at a wavelength of 532 nm was used as the light source. The laser beam was focused using a 100 mm focal length lens onto the sample’s surface. These experimental conditions produced an intensity of $1.236 \times 10^3 \text{ Wcm}^{-2}$ at the focal point. The laser beam radii at the focal point were measured using a CCD camera and were found to be $\omega_0 = 39.3 \mu\text{m}$. The Raleigh length, $Z_0 = \frac{(\pi\omega_0^2)}{\lambda}$, was determined to be $Z_0 = 9.11 \text{ mm}$, i.e., a value much larger than the film’s thickness, which is an essential prerequisite for the Z-scan experiments. The sample was moved along the Z-axis using a translation stage. An aperture with a diameter of 2 mm was located before the photodetector placed away from the beam’s focus. The transmittance of the aperture, S , was determined to be ~ 0.54 by $S = 1 - \exp\left(\frac{-2r_a^2}{\omega_a^2}\right)$. In this equation, r_a is the radius of the aperture, and ω_a is the beam waist on the aperture. Closed aperture data were obtained by measuring the transmitted beam intensity from the sample as a function of the sample’s position along the propagation direction. The measurements were repeated after removing the aperture in order to obtain the open aperture data [12]. In this work, the third-order non-linear optical parameters of the MoS₂ nanoflakes with different thicknesses were studied. In order to evaluate the effect of glass substrate to the Z-scan results, measuring the non-linearity of substrate without MoS₂ nanoflakes is performed and results show that glass substrate couldn’t show measurable effect on the Z-scan results.

RESULTS AND DISCUSSION

Structural Studies

The structural properties of the nanoflakes were investigated by XRD analysis. The X-ray diffraction pattern of the MoS₂ nanoflakes is shown in **Figure 1**. The main peak at $2\theta = 14.4^\circ$ is attributed to the (003) plane of 3R-MoS₂. The other corresponded peaks observed at $2\theta = 44.2^\circ$ and 58.2° are related to the (009) and (110) planes, respectively (RefCode: 01-077-0341). Furthermore, the peak at $2\theta = 37.3^\circ$ corresponds to the (200) plane of MoO₂, while another peak at $2\theta = 18.4^\circ$ is attributed to the (100) plane of MoO₂ (RefCode: 01-086-0135).

SEM micrographs of the MoS₂ nanoflakes, with different magnifications, are shown in **Figures 2A,B**. These images show the nanoflakes are grown with sharp edges and are in great abundance. On the other hand, AFM is applied in order to characterize the topography and surface quality of the prepared samples. **Figures 2C,D** represent the phase profile of the MoS₂ film and the corresponding height profile as typical. It indicates that the MoS₂ film is continuous and the average roughness is about 80 nm. This sample’s surface roughness or optical path is appropriate for z-scan measurement.”

Furthermore, the optical diffuse reflectance spectra were used to calculate the values of the optical band gap energies for

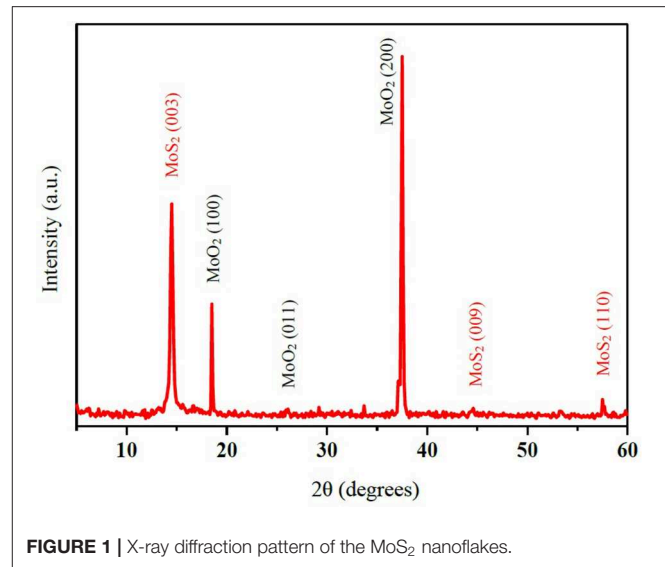


FIGURE 1 | X-ray diffraction pattern of the MoS₂ nanoflakes.

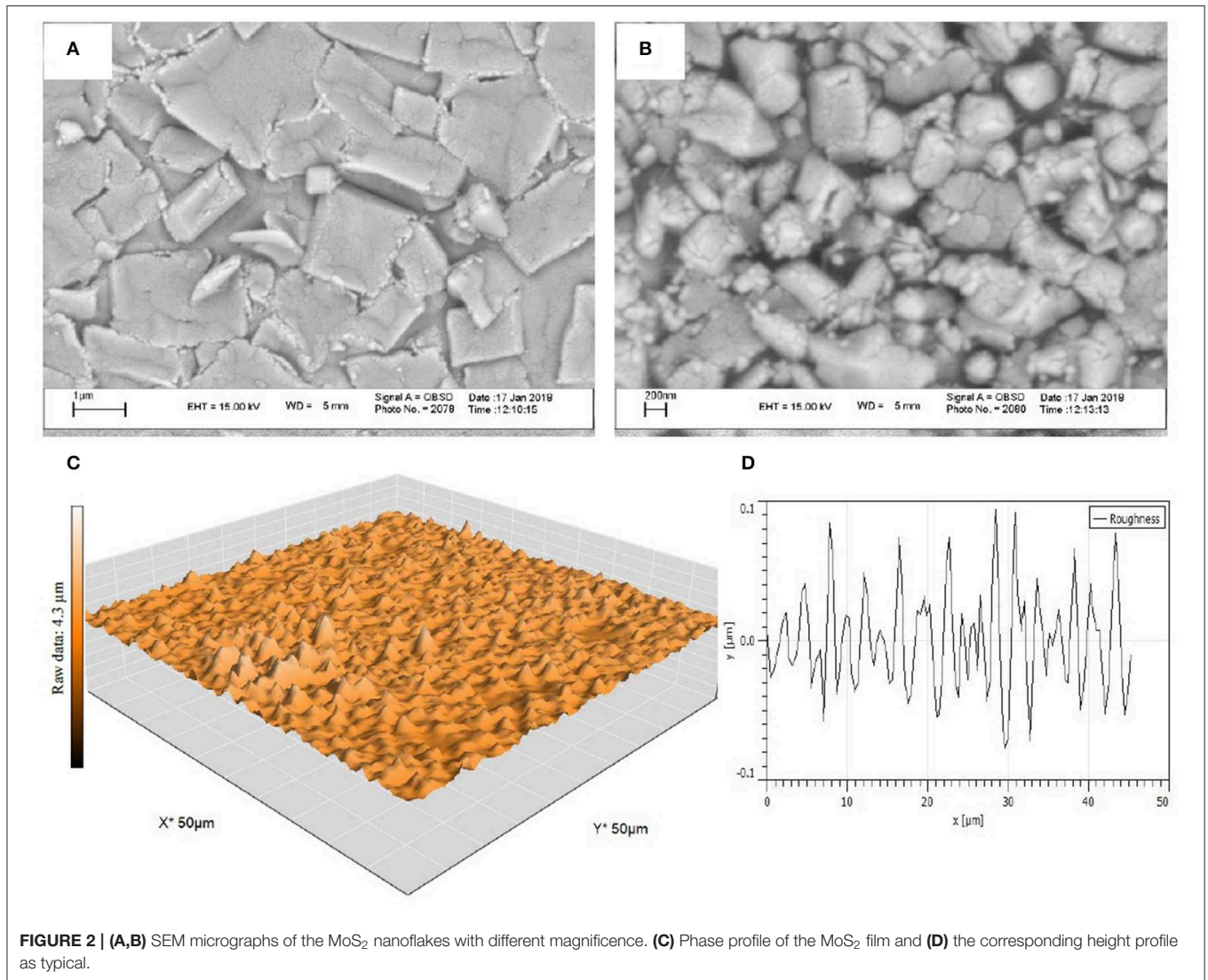
the MoS₂ nanoflakes. **Figure 3A** presents the diffuse reflectance spectra of the MoS₂ nanoflakes as a function of the wavelength. The results confirmed that the valence to conduction band transport of electrons, as a result of the absorption of the incident photon, leads to the reduction of the intensity of light at the relevant wavelength. Consequently, the relative percentage of the transmission to reflectance is diminished [23]. As it can be seen in **Figure 3A**, for the MoS₂ nanoflakes, by reducing the wavelength of the incident photons from 493 to 354 nm, the reflectance is decreased.

The band gap energy was calculated using a reflectance technique by the Mott and Davis theory [24]. Experimental values for the bandgap were attained by extrapolating the linear region of the curves to the zero absorption at $(\alpha h\nu)^2 = 0$, for the direct allowed transitions [12, 23]. **Figure 3B** displays the plot of $(\alpha h\nu)^2$ as a function of the incident photon energy ($h\nu$), for the direct allowed transitions of the MoS₂ nanoflakes. The optical band gap for the MoS₂ nanoflakes is calculated to be 1.91 eV.

Non-linear Optical Studies

In **Figure 4**, the closed aperture Z-scan curves of the MoS₂ nanoflakes are presented. In order to investigate the effect of samples’ thickness on the non-linear optical properties, films with different thicknesses of 150, 230, and 420 nm (sample 1, sample 2, and sample 3, respectively) were used. As can be seen, both films of the MoS₂ nanoflakes with thicknesses of 150 and 230 nm exhibit a pre-focal peak followed by a post-focal valley. Thus, inferring a negative value of the non-linear refractive index, indicating a self-defocusing behavior, for these samples [25, 26]. As the thickness of the film of the MoS₂ nanoflakes reaches to 420 nm, a pre-focal valley and a post-focal peak represent a positive value for the non-linear refractive index that signifies a self-focusing behavior in this sample.

Using the theoretical fit, via the experimental data of the closed aperture Z-scan curve, $\Delta T_{P-V} = T_P - T_V$ can be obtained. After the ΔT_{P-V} is derived from the difference of the transmittance



between the peak and valley, the magnitude of the phase shift $|\Delta\phi_0|$ is given by:

$$|\Delta\phi_0| = \frac{\Delta T_{P-V}}{0.406 (1 - S)^{0.27}} \quad (1)$$

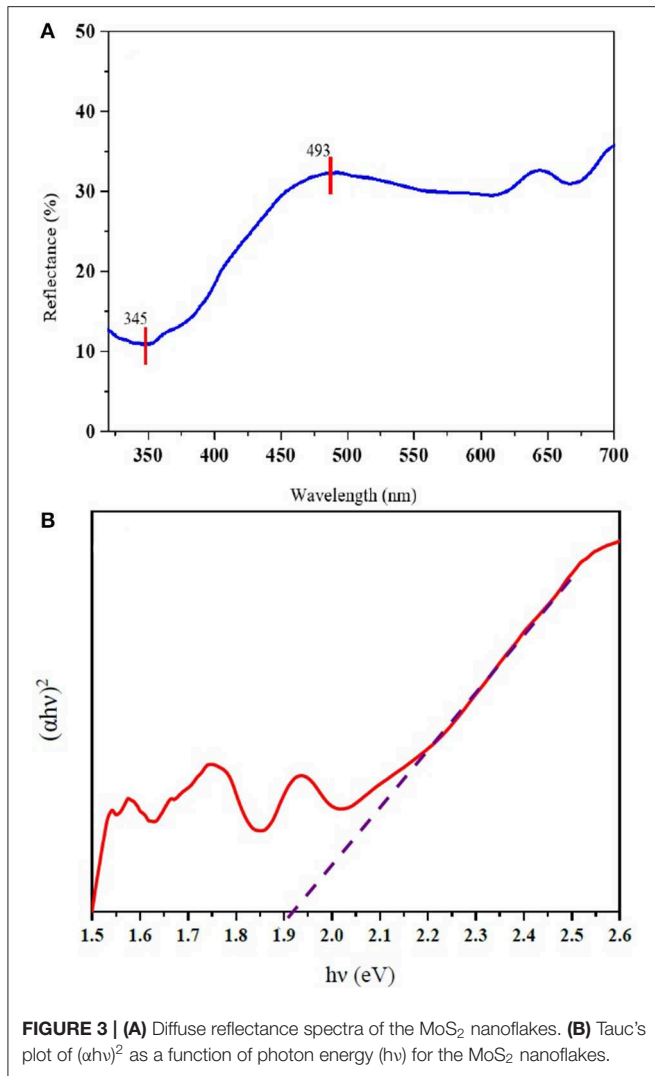
Here, S is the fraction of the beam transmitted through the aperture [25]. The non-linear refractive index, n_2 , can be calculated as:

$$n_2 = \frac{|\Delta\phi_0|}{\left(\frac{2\pi}{\lambda}\right) I_0 L_{\text{eff}}} \quad (2)$$

Where I_0 is the peak on-axis irradiance at the focal point, and the effective thickness can be expressed by the following form:

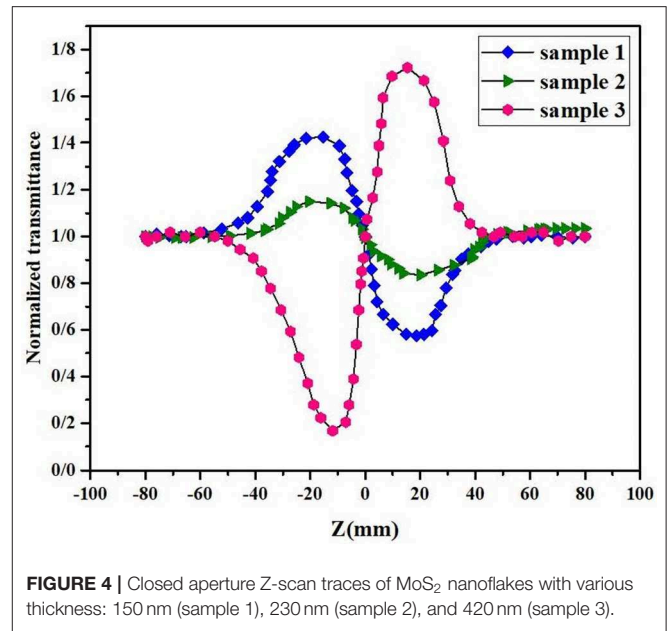
$$L_{\text{eff}} = \frac{(1 - e^{-\alpha_0 l})}{\alpha_0} \quad (3)$$

Where the linear absorption coefficient is $\alpha_0 = \frac{-1}{l} \ln\left(\frac{I}{I_0}\right)$, in which l is the thickness of the thin film, I and I_0 are the transmitted and the incident intensities, respectively [12, 25]. The results of the calculations are tabulated in **Table 1**. The linear absorption coefficient was measured through the conventional method, in the linear regime of the experiment. By changing the thickness of the film from 150 to 230 and 420 nm (sample 1, sample 2, and sample 3, respectively), the linear absorption coefficient varies from $9.51 \times 10^4 \text{ cm}^{-1}$ to $6.91 \times 10^4 \text{ cm}^{-1}$ and $4.21 \times 10^4 \text{ cm}^{-1}$, respectively. The closed aperture Z-scan results showed that the non-linear refractive index decreases substantially in the MoS₂ nanoflakes as the thickness of the films is increased from 150 to 230 nm. By further increasing the thickness of the film up to 420 nm, the sign of the non-linear refractive index changes from negative to positive, and also the magnitude of the non-linear refractive index increases to $3.92 \times 10^{-3} \text{ (cm}^2/\text{W)}$. It is worth mentioning that a CW laser was used and so a thermal effect is also accompanied by the non-linear



optical properties. This fact induces an enhancement in the obtained non-linear refractive index. So obviously, the thermo-optical non-linear response of the nanoflakes was investigated.

Recently, Jiang et al. investigated the role of the dipole moment in characterizing the non-linear optical behavior of materials [27]. To better understand the relevance between the dipole moments and the NLO responses, a flexible dipole model was suggested. This model clearly confirmed that the induced dipole oscillations via the external field, rather than the intrinsic dipole moments, determine the NLO responses. Therefore, in order to attain a large SHG effect, the focus should be on the non-centrosymmetric crystals containing flexible chemical bonds and not merely on the crystals with large polarity, since for the non-centrosymmetric crystals, the microscopic second-order susceptibility of the relevant active groups is additively superposed. So, the large third-order non-linear optical susceptibility in the MoS₂ nanoflakes could depend on the intrinsic dipole moments in the centrosymmetric crystal. On the other hand, the open-aperture Z-scan curves of the



MoS₂ nanoflakes, with three different thicknesses (150, 230, and 420 nm) in **Figure 5**, show a transmission minimum, when the samples reach the focal point. A normalized transmittance valley, indicating the existence of a two-photon absorption behavior, corresponding to positive sign non-linear absorption ($\beta > 0$).

The saturable absorption coefficient, β , can be determined by:

$$\beta = \frac{q_0}{I_0 L_{\text{eff}}} \tag{4}$$

q_0 can be obtained by fitting the experimental plots with the theoretical plots, where, the normalized change in the transmitted intensity ($\Delta T(Z) = T(Z) - 1$) can be approximated by the following equation:

$$\Delta T(Z) \approx \frac{q_0}{2\sqrt{2}} \left[\frac{1}{1 + \frac{Z^2}{Z_0^2}} \right] \tag{5}$$

Van Stryland et al. [25] the obtained values of the non-linear absorption coefficient, β , for the MoS₂ layers with different thicknesses are shown in **Table 1**.

Interestingly, the non-linear absorption coefficient increases substantially by augmenting the thickness of the MoS₂ layers.

The real and the imaginary parts of the third-order susceptibility, $\chi^{(3)}$, can be given in the following forms [28]:

$$\text{Re } \chi^3 (\text{esu}) = \left(\frac{10^{-4} \epsilon_0 c^2 n_0^2}{\pi} \right) n_2 \left(\frac{\text{cm}^2}{\text{W}} \right), \tag{6}$$

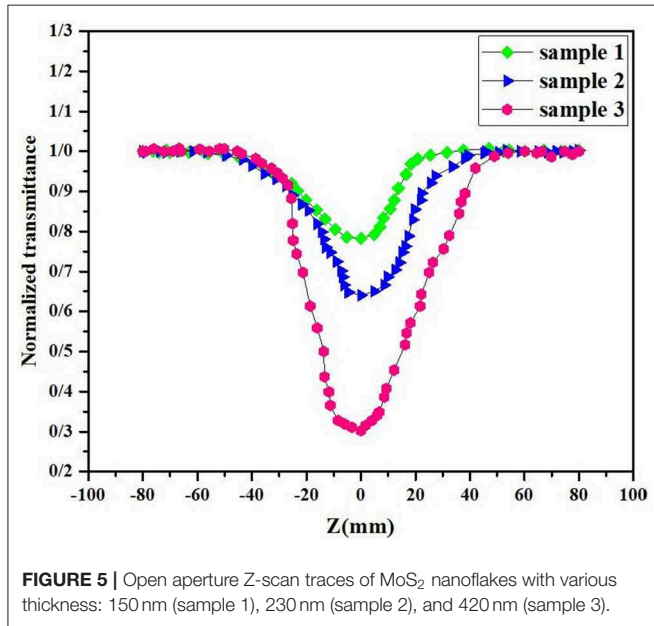
and

$$\text{Im } \chi^3 (\text{esu}) = \left(\frac{10^{-2} \epsilon_0 c^2 n_0^2 \lambda}{4\pi^2} \right) \beta \left(\frac{\text{cm}}{\text{W}} \right). \tag{7}$$

Where, ϵ_0 and c describe the vacuum permittivity and the speed of light in vacuum, respectively. Based on this theory, the

TABLE 1 | Non-linear optical parameters of the MoS₂ layers with different thicknesses.

MoS ₂ layer thickness	n_2 (cm ² /W)	β (cm ² /W)	$\chi^{(3)}$ (m ² /v ²)	$\text{Im}\chi^{(3)}$ (esu)	$\text{Re}\chi^{(3)}$ (esu)	γ (esu)
150 nm	-2.3×10^{-3}	63.07	0.18×10^{-7}	15.44×10^{-2}	1.32	1.50×10^{-32}
230 nm	-0.9×10^{-3}	72.86	0.07×10^{-7}	17.80×10^{-2}	0.51	0.61×10^{-32}
420 nm	3.9×10^{-3}	80.53	0.31×10^{-7}	19.68×10^{-2}	2.25	2.5×10^{-32}

**FIGURE 5** | Open aperture Z-scan traces of MoS₂ nanoflakes with various thickness: 150 nm (sample 1), 230 nm (sample 2), and 420 nm (sample 3).

results of the experiments are used to calculate the third-order susceptibility of the MoS₂ layers with different thicknesses. The results of these calculations are also presented in **Table 1**.

Finally, the corresponding second-order hyperpolarizability, γ , (i.e., the polarizability per molecule) is defined as:

$$\gamma = \frac{\chi^{(3)}}{NL^4} \quad (8)$$

Where N is the number of molecules per unit volume, and the local field correction factor, L , can be given by [29].

$$L = \frac{n_0^2 + 2}{3} \quad (9)$$

The values of γ , for the MoS₂ nanoflakes, are given in **Table 1**. The obtained values of $\chi^{(3)}$ and γ show that these two-dimensional structures exhibit large second-order

hyperpolarizability and signify their potential applications as NLO materials. Our study concluded that these two-dimensional materials are potential candidates for non-linear optical applications.

CONCLUSION

In conclusion, in this study, the non-linear thermo-optical response of the MoS₂ nanoflakes was investigated by means of the Z-scan technique. It was found that by increasing the thickness of the MoS₂ layers, the non-linear refractive index is increased, and the TPA process can occur with high probability, leading to the focusing of the Gaussian beam. Also, the MoS₂ nanoflakes were found to exhibit very large values of third-order non-linear susceptibility. Furthermore, the MoS₂ nanoflakes presented a self-defocusing behavior (i.e., negative non-linear refraction) in low thicknesses and a self-focusing behavior (positive non-linear refraction) in high thicknesses. Also, these nanoflakes showed two-photon absorption in all samples. Thus, the magnitude and the sign of the non-linear refractive index can be tuned by modifying the thickness of the MoS₂ nanoflakes. Also, the strong non-linear optical properties observed in these samples can be attributed to the intrinsic dipole moments in the centrosymmetric crystal. It has been demonstrated that these two-dimensional MoS₂ structures provide a suitable medium to observe and quantify two-photon absorption. It is concluded that the MoS₂ nanoflakes development, as non-linear optical materials and devices, is a new and exciting opportunity.

DATA AVAILABILITY STATEMENT

All datasets generated for this study are included in the article/supplementary material.

AUTHOR CONTRIBUTIONS

All authors listed have made a substantial, direct and intellectual contribution to the work, and approved it for publication.

REFERENCES

- Irimpan L, Krishnan B, Nampoory VPN, Radhakrishnan PJ. Luminescence tuning and enhanced nonlinear optical properties of nanocomposites of ZnO–TiO₂. *Colloid Interface Sci.* (2008) 324:99–104. doi: 10.1016/j.jcis.2008.04.056
- El Ouazzani H, Dabos-Seignon S, Gindre D, Iliopoulos K, Todorova M, Bakalska R, et al. Novel styrylquinolinium dye thin films deposited by pulsed laser deposition for nonlinear optical applications. *J Phys Chem.* (2012) 116:7144–52. doi: 10.1021/jp2118218

3. Lee HS, Min SW, Chang YG, Park MK, Nam T, Kim H, et al. MoS₂ nanosheet phototransistors with thickness-modulated optical energy gap. *Nano Lett.* (2012) **12**:3695–700. doi: 10.1021/nl301485q
4. Yin Z, Li H, Jiang L, Shi Y, Sun Y, Lu G, et al. Single-layer MoS₂ phototransistors. *ACS Nano.* (2011) **6**:74–80. doi: 10.1021/nn2024557
5. Dashora A, Ahuja U, Venugopalan K. Electronic and optical properties of MoS₂ thin films: feasibility for solar cells. *Comput Mater Sci.* (2013) **69**:216–21. doi: 10.1016/j.commatsci.2012.11.062
6. Ganatra R, Zhang Q. Few-layer MoS₂: a promising layered semiconductor. *ACS Nano.* (2014) **8**:4074–99. doi: 10.1021/nn405938z
7. Bao QL, Zhang H, Wang Y, Ni Z, Yan Y, Shen ZX, et al. Atomic-layer graphene as a saturable absorber for ultrafast pulsed lasers. *Adv Funct Mater.* (2009) **19**:3077–83. doi: 10.1002/adfm.200901007
8. Zhang H, Tang DY, Zhao LM, Bao QL, Loh KP. Large energy mode locking of an erbium-doped fiber laser with atomic layer graphene. *Opt Exp.* (2009) **17**:17630–5. doi: 10.1364/OE.17.017630
9. Li P, Liang B, Su M, Zhang Y, Zhao Y, Zhang M, et al. 980-nm Q-switched photonic crystal fiber laser by MoS₂ saturable absorber. *Appl Phys.* (2016) **122**:150. doi: 10.1007/s00340-016-6433-9
10. Khudyakov DV, Borodkin AA, Lobach AS, Mazin DD, Vartapetov SK. Optical nonlinear absorption of a few-layer MoS₂ under green femtosecond excitation. *Appl Phys B.* (2019) **125**:73. doi: 10.1007/s00340-019-7167-2
11. Li Y, Dong N, Zhang S, Zhang X, Feng Y, Wang K, et al. Two photon absorption in monolayer MoS₂. *Laser Photonics Rev.* (2015) **9**:427–34. doi: 10.1002/lpor.201500052
12. Mirershadi S, Ahmadi-Kandjani S, Zawadzka A, Rouhbakhsh H, Sahraoui B. Third order nonlinear optical properties of organometal halide perovskite by means of the Z-scan technique. *Chem Phys Lett.* (2016) **674**:7–13. doi: 10.1016/j.cplett.2016.01.04
13. Abdallah B, Zidan MD, Allahham A. Deposition of ZnS films by RF magnetron sputtering: structural and optical properties using Z-scan technique. *Int J Mod Phys.* (2019) **33**:1950348. doi: 10.1142/S021797921950348X
14. Majlesara MH, Dehghani Z. (2012). Measurement of nonlinear responses and optical limiting behavior of TiO₂/Ps nano-composite by single beam technique with different incident intensities. *Int J Mod Phys B.* **5**:277–83. doi: 10.1142/S2010194512002139
15. Arun Gaur DK, Sharma KS, Singh N. Photoexcited carrier lifetime in direct and indirect band gap crystals on the Z-Scan technique at 532 nm. *Int J Mod Phys.* (2007) **21**:3029–34. doi: 10.1142/S021797920703751X
16. Chung-Yu W, Guang-Yu G. Nonlinear optical properties of transition-metal dichalcogenide MX₂ (M = Mo, W; X = S, Se) monolayers and trilayers from first-principles calculations. *J Phys Chem C.* (2015) **119**:13268–76. doi: 10.1021/acs.jpcc.5b01866
17. Zhang S, Dong N, McEvoy N, O'Brien M, Winters S, Berner NC, et al. Direct observation of degenerate two-photon absorption and its saturation in WS₂ and MoS₂ monolayer and few-layer films. *ACS Nano.* (2015) **9**:7142–50. doi: 10.1021/acsnano.5b03480
18. Dhasmana N, Fadil D, Kaul AB, Thomas J. Investigation of nonlinear optical properties of exfoliated MoS₂ using Photoacoustic Zscan. *MRS Adv.* (2016) **1**:1–7. doi: 10.1557/adv.2016.456
19. Zhang H, Lu SB, Zheng J, Du J, Wen SC, Tang DY, et al. Molybdenum disulfide (MoS₂) as broadband saturable absorber for ultra-fast photonics. *Opt Exp.* (2014) **22**:7249–60. doi: 10.1364/OE.22.007249
20. Bikorimana S, Lama P, Walser A, Dorsinville R, Anghel S, Mitioglu A, et al. Nonlinear optical responses in two-dimensional transition metal dichalcogenide multilayer: WS₂, WSe₂, MoS₂ and Mo_{0.5}W_{0.5}S₂. *Opt Exp.* (2016) **24**:20685–95. doi: 10.1364/OE.24.020685
21. Bayesteh S, Mortazavi SZ, Reyhani A. Investigation on nonlinear optical properties of MoS₂ nanoflakes grown on silicon and quartz substrates. *J Phys D.* (2018) **51**:195302–10. doi: 10.1088/1361-6463/aab808
22. Bayesteh S, Mortazavi SZ, Reyhani A. Role of precursors' ratio for growth of two-dimensional MoS₂ structure and investigation on its nonlinear optical properties. *Thin Solid Films.* (2018) **663**:37–43. doi: 10.1016/j.tsf.2018.08.013
23. Mirershadi S, Sattari F, Golghasemi Sorkhabi S, Shokri AM. Pressure-induced optical band gap transition in methylammonium lead halide perovskites. *J Phys Chem.* (2019) **123**:12423–8. doi: 10.1021/acs.jpcc.9b02744
24. Mott NF, Davis EA. *Electronic Processes in Non-Crystalline Materials.* Oxford: Clarendon (1979).
25. Van Stryland EW, Sheik-Bahae M, Kuzyk MG, Dirk CW. *Z-Scan Measurements of Optical Nonlinearities Characterization Techniques and Tabulations for Organic Nonlinear Materials.* Marcel Dekker, Inc (1998). p. 655–692.
26. Joshi JH, Kalainathan S, Kanchan DK, Joshi MJ, Parikh KD. Effect of l-threonine on growth and properties of ammonium dihydrogen phosphate crystal. *Arab J Chem.* (2020) **13**:1532–50. doi: 10.1016/j.arabj.2017.12.005
27. Jiang X, Zhao S, Lin Z, Luo J, Bristwe PD, Guan X, et al. The role of dipole moment in determining the nonlinear optical behavior of materials: ab initio studies on quaternary molybdenum tellurite crystals. *J Mater Chem.* (2014) **2**:530–7. doi: 10.1039/C3TC31872A
28. Golian Y, Dorrani D. Effect of thickness on the optical nonlinearity of gold colloidal nanoparticles prepared by laser ablation. *Opt Quant Electron.* (2014) **46**:809–19. doi: 10.1007/s11082-013-9792-z
29. Couris S, Koudoumas E, Ruth AA, Leach SJ. Concentration and wavelength dependence of the effective third order susceptibility and optical limiting of C₆₀ in Toluene. *Phys At Mol Opt Phys.* (1995) **2**:4537–54. doi: 10.1088/0953-4075/28/20/015

Conflict of Interest: The authors declare that the research was conducted in the absence of any commercial or financial relationships that could be construed as a potential conflict of interest.

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